Accurate Measurement of the Gap of Graphene/h-BN Moiré Superlattice through Photocurrent Spectroscopy

Tianyi Han, ¹ Jixiang Yang, ¹ Qihang Zhang, ¹ Lei Wang, ^{2,3,4} Kenji Watanabe, ⁵ Takashi Taniguchi, ⁶ Paul L. McEuen, ^{2,3} and Long Juo ^{1,*}

¹Department of Physics, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA
²Kavli Institute at Cornell for Nanoscale Science, Ithaca, New York 14853, USA

³Laboratory of Atomic and Solid State Physics, Cornell University, Ithaca, New York 14853, USA

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Monolayer graphene aligned with hexagonal boron nitride (h-BN) develops a gap at the charge neutrality point (CNP). This gap has previously been extensively studied by electrical transport through thermal activation measurements. Here, we report the determination of the gap size at the CNP of graphene/h-BN superlattice through photocurrent spectroscopy study. We demonstrate two distinct measurement approaches to extract the gap size. A maximum of \sim 14 meV gap is observed for devices with a twist angle of less than 1°. This value is significantly smaller than that obtained from thermal activation measurements, yet larger than the theoretically predicted single-particle gap. Our results suggest that lattice relaxation and moderate electron-electron interaction effects may enhance the CNP gap in graphene/h-BN superlattice.

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Moiré superlattice composed of two-dimensional (2D) materials can be generated by either a twist between adjacent layers or a lattice mismatch between different materials. The resulting moiré potential could dramatically change the electronic and optical properties of 2D materials [1–12]. More recently, 2D moiré superlattices have emerged as a new platform to engineer topology and electron correlations. The periodicity of a moiré superlattice determines the Coulomb repulsion energy, while the moiré potential quenches the kinetic energy (with the help from external electric and magnetic fields)—bringing the system to a correlated regime. Experiments have demonstrated correlated insulator [13-19], superconductivity [20-23], and ferromagnetism [24-26] in a variety of 2D moiré superlattices. The accurate quantification of the moiré potential is crucial to better understand the underlying physics of these emerging phenomena and to utilize moiré superlattices to design and realize more exotic electronic ground states. For example, people found that when twisted bilayer graphene is further aligned with h-BN, ferromagnetism and quantized anomalous Hall effect emerge [24,25], where the estimation of the moiré potential at twisted bilayer graphene/h-BN interface is the key to account for the C_2 symmetry breaking of graphene. However, spectroscopy studies of these systems have so far remained limited.

Among various 2D moiré superlattices, monolayer graphene/h-BN superlattice is the first system that has

been extensively studied both theoretically and experimentally [1-6,8,9,12,27-35]. The boron and nitrogen atoms break the sublattice symmetry in graphene, which opens local band gaps at the charge neutrality point (CNP) of graphene [27]. However, it is calculated that such a local gap is nearly averaged out by different stacking order regions in a global moiré superlattice [28]. On the other hand, the moiré potential breaks the inversion symmetry, resulting in a global spectral gap opening at the CNP [29,33,35]. The periodicity of the moiré superlattice can modulate the gap size, where the maximum value of the moiré period is around 14 nm for 0° twist between the graphene and h-BN lattice [4]. Electron transport measurements of this gap size via thermal activation yield a maximum value in the range of 30–40 meV [1,3,4,6,7], which is 4-5 times bigger than the prediction from the single-particle model (~7 meV with the consideration of lattice relaxation [34]). The deviation is attributed to possible enhancement by electron-electron interactions [1,31,36]. Compared with various electron transport measurements, spectroscopic study of this gap remains scarce. It was claimed that a 38 meV gap exists at the CNP by using infrared transmission spectroscopy measurement [37]. However, their method of extrapolation from inter-Landau level transitions at high magnetic field is indirect. Together with the neglected variation of Fermi velocity at different energy, such a measurement suffers from many

⁴National Laboratory of Solid-State Microstructures, School of Physics and Collaborative Innovation Center of Advanced Microstructures, Nanjing University, Nanjing 210093, China

⁵Research Center for Functional Materials, National Institute for Materials Science, 1-1 Namiki, Tsukuba 305-0044, Japan ⁶International Center for Materials Nanoarchitectonics, National Institute for Materials Science, 1-1 Namiki, Tsukuba 305-0044, Japan

experimental uncertainties. Recently, a planer tunneling spectroscopy experiment observed a gap size of around 16 meV [38], significantly smaller than that in all other experiments.

Here we report the systematic study of the CNP gap in graphene/h-BN superlattice by photocurrent spectroscopy. We demonstrate two ways to determine the gap size: one is based on the onset energy of interband optical transition at zero magnetic field, while the other one is based on the splitting of Landau level (LL) transition peaks at finite magnetic field. Both experimental approaches show consistent results, where the maximum gap size is around 14 meV. This value is consistent with the tunneling spectroscopy experiment and substantially smaller than most transport results.

Figure 1(a) shows an optical image of the device (device C). We fabricated high-quality monolayer graphene Corbino devices encapsulated between two flakes of h-BN (except for device A, which is a van der Pauw structure device; see Supplemental Material [39] and Ref. [40] for device fabrication details). The graphene layer forms a small twist angle θ with either the top or bottom h-BN flake. The layered stack is placed on either a graphite local bottom gate or a SiO₂/Si global bottom gate. Figure 1(c) shows the Landau fan diagram of our Corbino device C. Pronounced LLs develop at magnetic field less than 0.5 T, demonstrating the device is of high quality. Satellite conductance dips arising from the moiré gap are observed at $V_q \sim \pm 6$ V, which develop into separate sets of LLs. Based on the LL degeneracy and the positions of satellite conductance dips, we can extract a moiré wavelength of \sim 14 nm and a twist angle of \sim 0.1° for this device. We use the same method to extract the moiré wavelength and twist angle in other devices. See details in the Supplemental Material [39].

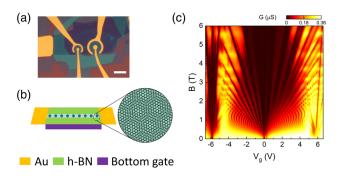


FIG. 1. Device structure and transport characterization. (a) Optical image of a Corbino geometry device. Scale bar, 10 μ m. (b) Schematic of the device structure: monolayer graphene sandwiched by h-BN, with either a $\mathrm{SiO_2/Si}$ or graphite bottom gate. The moiré superlattice exists between monolayer graphene and either top or bottom h-BN flake. (c) Characteristic Landau fan diagram of the monolayer graphene Corbino device C with moiré potential. Satellite conductance dips emerge at around $V_q = \pm 6 \ \mathrm{V}$.

We then use Fourier transform infrared (FTIR) photocurrent spectroscopy [41,42] to measure the optical absorption spectrum (see measurement details in Supplemental Material [39]). In the quantum Hall regime, the fluctuation of the edge current in devices would contribute to a large background noise, which would obscure our signal from inter-LL optical transitions. Thus, we fabricate the graphene/h-BN devices in a Corbino geometry as shown in Fig. 1(a) to eliminate the edge channel and only collect photocurrent signal from the bulk. We mainly show the photocurrent data of three high-quality devices in the main text, i.e., devices A, B, and C. The data of other devices are included in the Supplemental Material [39]. All data were collected at a base temperature of 2 K.

We demonstrate two approaches of determining the gap size at the CNP in graphene/h-BN superlattice through the photocurrent spectroscopy. The first one starts with photocurrent spectroscopy at zero magnetic field. By gating we placed the Fermi level at the CNP. With a gap opened at the CNP, interband transitions are forbidden at low energy, while they start to appear at a threshold energy. This threshold energy provides a first measurement of the band gap size which can be clearly resolved in Fig. 2(a). The device used here has a moiré wavelength of 10.4 nm and a corresponding twist angle of 1.0° (device A). Because of thermal and disorder broadening, the expected step function of optical absorption is smeared, and so we used the midpoint of the rising slope in spectrum to determine $T_0 = 14.9$ meV. This gap value is 2–3 times smaller than the previous reported value in transport measurement [1,3,4,6,7]. We further verify our results by applying a small out-of-plane B field to the device, while fixing the Fermi level at the CNP. LLs emerge at a magnetic field as low as 0.1 T, which is signified by the sharp inter-LL optical transitions T_1 and T_2 as traced by dashed curves in Fig. 2(a). We illustrate the allowed inter-LL optical transitions in Fig. 2(b). The selection rule for inter-LL transitions is $\Delta |N| = \pm 1$, where N is the LL index. When the Fermi level is in the CNP gap, allowed LL transitions are labeled in the diagram as T_1 , T_2 , etc. In this picture, the energy of the T_1 transition should be described by a simple model $E = \sqrt{2e\hbar v_F^2 B + (\Delta/2)^2} + \Delta/2$. Through a simple transformation, we obtain $E = 2e\hbar v_F^2 B/E + \Delta$. We tested this model by summarizing experimentally extracted T_0 and T_1 as shown in Fig. 2(c). All the data can be well fitted with a gap value $\Delta = 14.0 \pm 0.6$ meV and Fermi velocity $v_F \sim 1.21(\pm 0.02) \times 10^6$ m/s. We also fit the T_0 and T_2 with the formula of the T_2 transition E_{T_2} $\sqrt{2e\hbar v_F^2 B + (\Delta/2)^2} + \sqrt{2 \times (2e\hbar v_F^2 B) + (\Delta/2)^2}$ and extract a gap value $\Delta = 15.3 \pm 1.2 \text{ meV}$ and a Fermi velocity $v_F \sim 1.24(\pm 0.01) \times 10^6$ m/s, which is on the same order of magnitude with the results from the T_1 transition. Details of the fitting of T_2 transition are included in the Supplemental Material [39]. As we have a

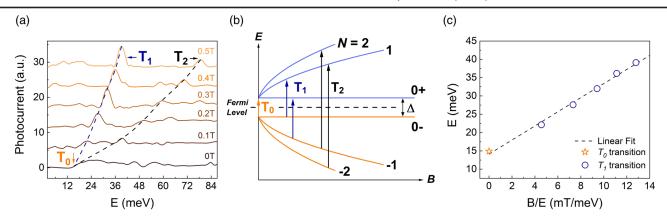


FIG. 2. Photocurrent spectra with the Fermi level located at the CNP. (a) Photocurrent spectra at magnetic field B=0–0.5 T. At B=0 T, the optical transition has a threshold energy of T_0 , which corresponds to the band gap Δ . When B increases, LLs are formed and inter-LL transitions labeled as T_1 and T_2 emerge from the continuous spectrum at 0 T. Spectra are shifted vertically for clarity. Dashed curves are guide lines of the T_1 and T_2 transitions. (b) Schematic illustrating the inter-LL transition T_1 and T_2 that are allowed by the optical selection rule $\Delta |N| = \pm 1$. At the low magnetic field limit, they both converge to T_0 transition energy Δ . (c) Extraction of Δ from the fitting of T_0 (14.9 meV marked by star symbol in orange) and inter-LL transition T_1 by using $E = 2e\hbar v_F^2 B/E + \Delta$.

high-quality device and a large signal-to-noise ratio of our FTIR photocurrent spectrum, we can directly resolve the optical absorption information at B < 0.5 T and measure the CNP gap size.

We adopted a second approach to extract the gap size at the CNP through inter-LL transitions at finite magnetic fields. The idea is illustrated in the schematic in Fig. 3(a). The zeroth LL of the massive Dirac fermion is located at the bottom of conduction band in the K valley and the top of valence band at the K' valley. This valley polarization does not result in significant peak splitting in optical absorption when the Fermi level is at the CNP and the filling factor at $\nu = 0$, since the inter-LL transitions $(-1 \rightarrow 0, K)$ and $(0 \rightarrow 1, K')$ as indicated by red arrows are mostly degenerate. However, when the Fermi level is placed between LL N=1 and 0 in the K valley or N=-1 and 0 in the K' valley, Pauli blocking forbids one transition that was allowed at $\nu = 0$ and enables another inter-LL transition. This change in optical transitions is illustrated by blue (black) arrows when the filling factor equals +2 (-2), respectively, in Fig. 3(a). Therefore, the optical absorption spectrum features two transition peaks that are separate in energy by Δ , allowing us to determine the CNP gap independently from the first experimental approach. We utilized the bottom gate to tune the Fermi level and obtained typical photocurrent spectra for different filling factors as shown in Figs. 3(b) and 3(c) for devices B and C. At $\nu = 0$, the photocurrent spectrum features a single peak in the range of T_1 transitions. The relatively wide peak width in Fig. 3(c) indicates a small splitting due to electronhole asymmetry of the band structure, which does not affect our conclusion. At both $\nu = +2$ and -2, the spectrum features two distinct peaks that are widely separated by an energy much bigger than the peak width. This result agrees with our expectation based on Fig. 3(a) and allowed us to extract a CNP gap size of 4.5 meV for device B and 11.9 meV for device C. We further explore the peak splitting as a function of magnetic field for device B as shown in Fig. 3(d). The filling factor at all B fields are fixed at $\nu = +2$. The splitting remains at \sim 4.5 meV with small

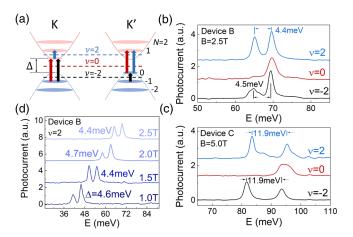


FIG. 3. Extraction of Δ from inter-LL transitions at different filling factors. (a) Schematic showing allowed inter-LL transitions in the K and K' valleys of graphene when the Fermi level is adjusted to filling factor $\nu = -2$ (black dashed line and arrows), $\nu = 0$ (red), and $\nu = 2$ (blue). The zeroth LL is located at the bottom of the conduction band (top of the valence band) in the K (K') valley—lifting the valley degeneracy of inter-LL transitions. (b),(c) Photocurrent spectra of device B at 2.5 T and device C at 5.0 T. In both cases, the two allowed inter-LL transitions remain degenerate at $\nu = 0$, resulting in a single absorption peak. At both $\nu = 2$ and -2, the two allowed transitions are split by the gap energy Δ . Transitions at $\nu = 2, 0, -2$ correspond to blue, red, and black arrows in (a), respectively. (d) Photocurrent spectra at $\nu=2$ for device B as a function of magnetic field from 1.0 to 2.5 T. The splitting between two inter-LL transitions in all spectra are close to 4.5 meV as labeled.

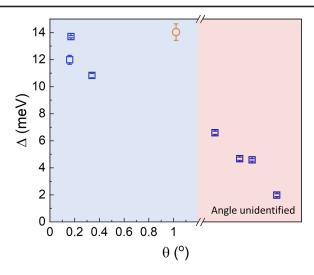


FIG. 4. Summary of the extracted gap sizes Δ from devices with different moiré periods. The blue shaded area includes devices where the twist angle between graphene and h-BN can be extracted from the satellite peak position in transport [39]. The pink shaded area includes devices with relatively large twist angles, which cannot be determined due to limited gate voltage range in experiment. Error bars show the standard deviations of multiple measurements at different magnetic fields. The orange circle data point is extracted via the first measurement scheme from device A, and other blue square data points are acquired via the second method.

variations. This consistent value in a wide range of magnetic field proves the validity of our model and experimental methodology.

In Fig. 4 we summarize the gap sizes measured in all devices through the photocurrent spectroscopy with the two different approaches. For devices with a small twist angle, we are able to extract the moiré superlattice period (as listed in the x axis in the blue shaded area in Fig. 4) and the twist angle. We also measured devices with bigger twist angles than 1°, but due to the limited charge density that can be achieved by gating, we do not know exactly what their twist angles are. The band gap sizes extracted from these devices are listed in pink shaded area and are all smaller than the ones with twist angles less than 1°. This trend is phenomenologically consistent with the single-particle picture. We note that the single data point at $\sim 1^{\circ}$ with a relatively larger error bar (denoted by the orange circle in Fig. 4) is extracted from the onset energy of interband transition and the fitting, which may be less accurate than other data points in Fig. 4 that are directly extracted from the energy splitting of the LL transition spectra.

In all of our measured devices with different twist angles, the gap sizes at the CNP (~14 meV at maximum) are all significantly smaller than the sizes reported from previous transport measurements (~30–40 meV) [1,3,4,6,7]. This observation is contrary to experience: the transport measured gap is usually smaller than the true band gap due to the existence of in-gap states. However, such

kind of disagreement between thermal activation and spectroscopic measurement is not only seen in the case of graphene/h-BN superlattice. For example, in the recent study of the moiré gap in twisted bilayer graphene, the transport measurement extracted a ~32 meV gap at full filling of the valence band side through thermal activation measurement [13], while the scanning tunneling spectroscopy (STS) study extracted a ~15 meV gap [43]. On the conduction band side, the transport measurement extracted a ~40 meV gap [13] while the STS study extracted a \sim 25 meV gap [44]. We believe the value extracted from our measurement is closer to the true gap size as we performed spectroscopy, where the energy scale can be directly read from our data. We noted that a recent planer tunneling spectroscopy measurement observed a gap size at the CNP very close to ours [38].

We would also like to discuss the plausibility of possible excitonic effects in explaining the discrepancy between our experiment and previous transport experiments. In semiconductors, excitations of bound exciton states result in an optical band gap that is smaller than the true single-particle band gap. However, we believe that the excitonic effect in monolayer graphene/h-BN gap is negligible. The strength of excitonic effects is usually proportional to the flatness of the band, which can be quantified by the effective mass of the carriers. The effective mass in gapped monolayer graphene is related to the gap size as $\Delta = 2m^*v_F^2$. With $\Delta \sim 14 \text{ meV}$ and $v_F \sim 1.21 \times 10^6 \text{ m/s}$ extracted from device A, $m^* \sim 0.84 \times 10^{-3} m_0$, where m_0 is the bare electron mass. This is much smaller than that in bilayer graphene $(m^* \sim 0.04m_0$ [45]). So, excitonic effects and exciton binding energy in this gap are expected to be much weaker in monolayer graphene compared to those in bilayer graphene. Experimentally, we only observed a step-function-like photocurrent spectrum at zero magnetic field as shown in Fig. 2(a), in contrast to sharp exciton peaks as shown in bilayer graphene in similar sample configurations [41]. In bilayer graphene, the exciton binding energy at a band gap of 30 meV is only ~5 meV [41]. Since the excitonic effect should be weaker in monolayer graphene than in bilayer graphene, the exciton binding energy is likely to be smaller than 5 meV—too small to explain the difference between 30-40 meV in previous measurements [1,3,4,6,7] and 14 meV in our experiment. At the same time, in our second approach to extract the band gap size, similar excitonic effects on inter-LL transitions should happen for both transitions at $\nu = +2$ and -2. By subtracting their transition energies, the effect of exciton binding energy on determining the single-particle band gap is presumably canceled out.

Theoretically, in the single-particle picture for a superlattice with 0° twist angle, a continuum model gives a ~2 meV gap at the CNP [33]. A previous density functional theory calculation obtained a ~4 meV gap [28], which is on the same order of magnitude. Additional lattice relaxation enlarges the gap size to \sim 7 meV [34,35], which is around half the value of our results. In addition to the single-particle model, many-body electron interaction effects may also enhance the gap size. Interacting Dirac particles in graphene are subjected to the A-B sublattice-dependent potential in the superlattice. The interactions can create sublattice correlation that can further amplify the potential and thus increase the gap [31]. Theoretical calculations obtain \sim 20 meV gap with both lattice relaxation and interaction effects taken into consideration [34]. This value is very close to our results.

In summary, we employed FTIR photocurrent spectroscopy to measure high-quality devices of h-BNencapsulated monolayer graphene. We observed a band gap of less than 14 meV at nearly 0° twist angle. This quantitative information should aid in the better understanding of the physics of graphene-based 2D moiré superlattices. Particularly, it allows for more accurate modeling of correlated electron physics and topological phenomena in twisted bilayer graphene [13,20–22,24,25], ABC trilayer graphene/h-BN [14,23,26], twisted double bilayer graphene [15,16], and twisted monolayer-bilayer graphene [46,47]. The (magneto-)FTIR photocurrent spectroscopy could also be further extended to spectroscopic measurement of low-energy electronic band structures of 2D moiré superlattices, as well as symmetry broken ground states in the quantum Hall regime [1,7,48–56].

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- [2] L. Ponomarenko, R. Gorbachev, G. Yu, D. Elias, R. Jalil, A. Patel, A. Mishchenko, A. Mayorov, C. Woods, J. Wallbank, M. Mucha-Kruczynski, B. Piot, M. Potemski, I. Grigorieva, K. Novoselov, F. Guinea, V. Fal'ko, and A. Geim, Nature (London) 497, 594 (2013).
- [3] C. Woods et al., Nat. Phys. 10, 451 (2014).
- [4] R. Ribeiro-Palau, C. Zhang, K. Watanabe, T. Taniguchi, J. Hone, and C. R. Dean, Science **361**, 690 (2018).
- [5] M. Yankowitz, J. Jung, E. Laksono, N. Leconte, B. L. Chittari, K. Watanabe, T. Taniguchi, S. Adam, D. Graf, and C. R. Dean, Nature (London) 557, 404 (2018).
- [6] N. R. Finney, M. Yankowitz, L. Muraleetharan, K. Watanabe, T. Taniguchi, C. R. Dean, and J. Hone, Nat. Nanotechnol. 14, 1029 (2019).
- [7] L. Wang, Y. Gao, B. Wen, Z. Han, T. Taniguchi, K. Watanabe, M. Koshino, J. Hone, and C. R. Dean, Science 350, 1231 (2015).
- [8] Z. Shi, C. Jin, W. Yang, L. Ju, J. Horng, X. Lu, H. A. Bechtel, M. C. Martin, D. Fu, J. Wu, K. Watanabe, T. Taniguchi, Y. Zhang, X. Bai, E. Wang, G. Zhang, and F. Wang, Nat. Phys. 10, 743 (2014).
- [9] M. Yankowitz, J. Xue, D. Cormode, J. D. Sanchez-Yamagishi, K. Watanabe, T. Taniguchi, P. Jarillo-Herrero, P. Jacquod, and B. J. LeRoy, Nat. Phys. 8, 382 (2012).
- [10] C. Jin, E. C. Regan, A. Yan, M. I. B. Utama, D. Wang, S. Zhao, Y. Qin, S. Yang, Z. Zheng, S. Shi, K. Watanabe, T. Taniguchi, S. Tongay, A. Zettl, and F. Wang, Nature (London) 567, 76 (2019).
- [11] C. Jin, E. C. Regan, D. Wang, M. I. B. Utama, C.-S. Yang, J. Cain, Y. Qin, Y. Shen, Z. Zheng, K. Watanabe, T. Taniguchi, S. Tongay, A. Zettl, and F. Wang, Nat. Phys. 15, 1140 (2019).
- [12] A. Eckmann, J. Park, H. Yang, D. Elias, A. S. Mayorov, G. Yu, R. Jalil, K. S. Novoselov, R. V. Gorbachev, M. Lazzeri, A. K. Geim, and C. Casiraghi, Nano Lett. 13, 5242 (2013)
- [13] Y. Cao, V. Fatemi, A. Demir, S. Fang, S. L. Tomarken, J. Y. Luo, J. D. Sanchez-Yamagishi, K. Watanabe, T. Taniguchi, E. Kaxiras, R. C. Ashoori, and P. Jarillo-Herrero, Nature (London) 556, 80 (2018).
- [14] G. Chen, L. Jiang, S. Wu, B. Lyu, H. Li, B. L. Chittari, K. Watanabe, T. Taniguchi, Z. Shi, J. Jung, Y. Zhang, and F. Wang, Nat. Phys. 15, 237 (2019).
- [15] X. Liu, Z. Hao, E. Khalaf, J. Y. Lee, Y. Ronen, H. Yoo, D. H. Najafabadi, K. Watanabe, T. Taniguchi, A. Vishwanath, and P. Kim, Nature (London) 583, 221 (2020).
- [16] Y. Cao, D. Rodan-Legrain, O. Rubies-Bigorda, J. M. Park, K. Watanabe, T. Taniguchi, and P. Jarillo-Herrero, Nature (London) 583, 215 (2020).
- [17] Y. Tang, L. Li, T. Li, Y. Xu, S. Liu, K. Barmak, K. Watanabe, T. Taniguchi, A. H. MacDonald, J. Shan, and K. F. Mak, Nature (London) 579, 353 (2020).
- [18] E. C. Regan, D. Wang, C. Jin, M. I. B. Utama, B. Gao, X. Wei, S. Zhao, W. Zhao, Z. Zhang, K. Yumigeta, M. Blei, J. D. Carlström, K. Watanabe, T. Taniguchi, S. Tongay, M. Crommie, A. Zettl, and F. Wang, Nature (London) 579, 359 (2020).
- [19] L. Wang, E.-M. Shih, A. Ghiotto, L. Xian, D. A. Rhodes, C. Tan, M. Claassen, D. M. Kennes, Y. Bai, B. Kim, K. Watanabe, T. Taniguchi, X. Zhu, J. Hone, A. Rubio, A. N. Pasupathy, and C. R. Dean, Nat. Mater. 19, 861 (2020).

^{*}longju@mit.edu

^[1] B. Hunt, J. D. Sanchez-Yamagishi, A. F. Young, M. Yankowitz, B. J. LeRoy, K. Watanabe, T. Taniguchi, P. Moon, M. Koshino, P. Jarillo-Herrero, and R. C. Ashoori, Science 340, 1427 (2013).

- [20] Y. Cao, V. Fatemi, S. Fang, K. Watanabe, T. Taniguchi, E. Kaxiras, and P. Jarillo-Herrero, Nature (London) 556, 43 (2018).
- [21] M. Yankowitz, S. Chen, H. Polshyn, Y. Zhang, K. Watanabe, T. Taniguchi, D. Graf, A. F. Young, and C. R. Dean, Science 363, 1059 (2019).
- [22] X. Lu, P. Stepanov, W. Yang, M. Xie, M. A. Aamir, I. Das, C. Urgell, K. Watanabe, T. Taniguchi, G. Zhang, A. Bachtold, A. H. MacDonald, and D. K. Efetov, Nature (London) 574, 653 (2019).
- [23] G. Chen, A. L. Sharpe, P. Gallagher, I. T. Rosen, E. J. Fox, L. Jiang, B. Lyu, H. Li, K. Watanabe, T. Taniguchi, J. Jung, Z. Shi, D. Goldhaber-Gordon, Y. Zhang, and F. Wang, Nature (London) 572, 215 (2019).
- [24] A. L. Sharpe, E. J. Fox, A. W. Barnard, J. Finney, K. Watanabe, T. Taniguchi, M. Kastner, and D. Goldhaber-Gordon, Science 365, 605 (2019).
- [25] M. Serlin, C. Tschirhart, H. Polshyn, Y. Zhang, J. Zhu, K. Watanabe, T. Taniguchi, L. Balents, and A. Young, Science 367, 900 (2020).
- [26] G. Chen, A. L. Sharpe, E. J. Fox, Y.-H. Zhang, S. Wang, L. Jiang, B. Lyu, H. Li, K. Watanabe, T. Taniguchi, Z. Shi, S. Todadri, D. Goldhaber-Gordon, Y. Zhang, and F. Wang, Nature (London) 579, 56 (2020).
- [27] G. Giovannetti, P. A. Khomyakov, G. Brocks, P. J. Kelly, and J. Van den Brink, Phys. Rev. B 76, 073103 (2007).
- [28] B. Sachs, T.O. Wehling, M.I. Katsnelson, and A.I. Lichtenstein, Phys. Rev. B 84, 195414 (2011).
- [29] M. Kindermann, B. Uchoa, and D. L. Miller, Phys. Rev. B 86, 115415 (2012).
- [30] J. R. Wallbank, A. A. Patel, M. Mucha-Kruczyński, A. K. Geim, and V. I. Fal'ko, Phys. Rev. B 87, 245408 (2013).
- [31] J. C. W. Song, A. V. Shytov, and L. S. Levitov, Phys. Rev. Lett. 111, 266801 (2013).
- [32] J. Jung, A. Raoux, Z. Qiao, and A. H. MacDonald, Phys. Rev. B 89, 205414 (2014).
- [33] P. Moon and M. Koshino, Phys. Rev. B 90, 155406 (2014).
- [34] J. Jung, A. M. DaSilva, A. H. MacDonald, and S. Adam, Nat. Commun. 6, 6308 (2015).
- [35] J. Jung, E. Laksono, A. M. DaSilva, A. H. MacDonald, M. Mucha-Kruczyński, and S. Adam, Phys. Rev. B 96, 085442 (2017).
- [36] M. Bokdam, T. Amlaki, G. Brocks, and P. J. Kelly, Phys. Rev. B 89, 201404(R) (2014).
- [37] Z.-G. Chen, Z. Shi, W. Yang, X. Lu, Y. Lai, H. Yan, F. Wang, G. Zhang, and Z. Li, Nat. Commun. 5, 4461 (2014).
- [38] H. Kim, N. Leconte, B. L. Chittari, K. Watanabe, T. Taniguchi, A. H. MacDonald, J. Jung, and S. Jung, Nano Lett. 18, 7732 (2018).
- [39] See Supplemental Material at http://link.aps.org/ supplemental/10.1103/PhysRevLett.126.146402 for details

- of the device fabrication process, FTIR photocurrent measurement scheme, method to extract the moiré period and twist angle, fitting of the T_2 transition, and supplemental data of other measured devices, which includes Refs. [9,40,41].
- [40] L. Wang, I. Meric, P. Huang, Q. Gao, Y. Gao, H. Tran, T. Taniguchi, K. Watanabe, L. Campos, D. Muller, J. Guo, P. Kim, J. Hong, K. Shepard, and C. Dean, Science 342, 614 (2013).
- [41] L. Ju, L. Wang, T. Cao, T. Taniguchi, K. Watanabe, S. G. Louie, F. Rana, J. Park, J. Hone, F. Wang, and P. L. McEuen, Science 358, 907 (2017).
- [42] L. Ju, L. Wang, X. Li, S. Moon, M. Ozerov, Z. Lu, T. Taniguchi, K. Watanabe, E. Mueller, F. Zhang, D. Smirnov, F. Rana, and P. L. McEuen, Nat. Commun. 11, 2941 (2020).
- [43] Y. Xie, B. Lian, B. Jäck, X. Liu, C.-L. Chiu, K. Watanabe, T. Taniguchi, B. A. Bernevig, and A. Yazdani, Nature (London) 572, 101 (2019).
- [44] Y. Choi, J. Kemmer, Y. Peng, A. Thomson, H. Arora, R. Polski, Y. Zhang, H. Ren, J. Alicea, G. Refael, F. von Oppen, K. Watanabe, T. Taniguchi, and S. Nadj-Perge, Nat. Phys. 15, 1174 (2019).
- [45] K. Zou, X. Hong, and J. Zhu, Phys. Rev. B 84, 085408 (2011).
- [46] S. Chen, M. He, Y.-H. Zhang, V. Hsieh, Z. Fei, K. Watanabe, T. Taniguchi, D. H. Cobden, X. Xu, C. R. Dean, and M. Yankowitz, Nat. Phys. 17, 374 (2021).
- [47] H. Polshyn, J. Zhu, M. Kumar, Y. Zhang, F. Yang, C. Tschirhart, M. Serlin, K. Watanabe, T. Taniguchi, A. MacDonald, and A. Young, Nature (London) 588, 66 (2020).
- [48] A. F. Young, C. R. Dean, L. Wang, H. Ren, P. Cadden-Zimansky, K. Watanabe, T. Taniguchi, J. Hone, K. L. Shepard, and P. Kim, Nat. Phys. 8, 550 (2012).
- [49] A. Young, J. Sanchez-Yamagishi, B. Hunt, S. Choi, K. Watanabe, T. Taniguchi, R. Ashoori, and P. Jarillo-Herrero, Nature (London) 505, 528 (2014).
- [50] A. Zibrov, E. Spanton, H. Zhou, C. Kometter, T. Taniguchi, K. Watanabe, and A. Young, Nat. Phys. 14, 930 (2018).
- [51] C. R. Dean, L. Wang, P. Maher, C. Forsythe, F. Ghahari, Y. Gao, J. Katoch, M. Ishigami, P. Moon, M. Koshino, T. Taniguchi, K. Watanabe, K. Shepard, J. Hone, and P. Kim, Nature (London) 497, 598 (2013).
- [52] I. F. Herbut, Phys. Rev. B 75, 165411 (2007).
- [53] K. Nomura, S. Ryu, and D.-H. Lee, Phys. Rev. Lett. **103**, 216801 (2009).
- [54] M. Kharitonov, Phys. Rev. B 85, 155439 (2012).
- [55] M. Kharitonov, Phys. Rev. Lett. 109, 046803 (2012).
- [56] J. Alicea and M. P. A. Fisher, Phys. Rev. B **74**, 075422 (2006).